

Solid State Relay OCMOS FET

PS7211-2A

8-PIN SOP 100 V BREAK DOWN VOLTAGE 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7211-2A is a solid state relay containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

It is suitable for analog signal control because of its low offset and high linearity.

* FEATURES

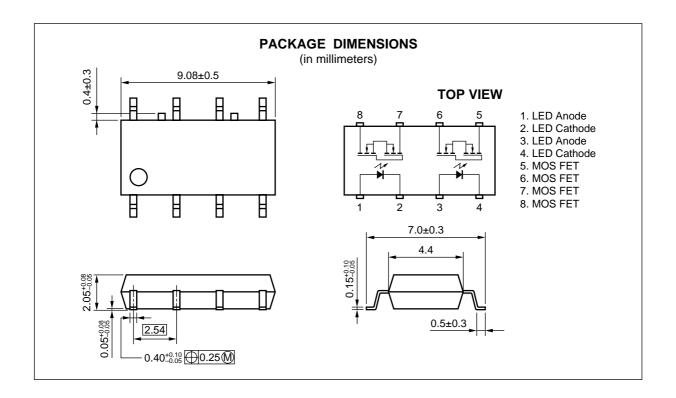
- 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small and thin package (8-pin SOP, Height = 2.1 mm)
- · Low offset voltage
- Ordering number of taping product: PS7211-2A-F3, F4
- UL approved: File No. E72422 (S)
- BSI approved: No. 8241/8242
- CSA approved: No. CA 101391

APPLICATIONS

- · Exchange equipment
- Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7211-2A	8-pin SOP	Magazine case 45 pcs	PS7211-2A
PS7211-2A-F3		Embossed Tape 1 500 pcs/reel	
PS7211-2A-F4			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	lF	50	mA	
	Reverse Voltage	VR	5.0	V	
	Power Dissipation	PD	50	mW/ch	
	Peak Forward Current ^{*1}	IFP	1	Α	
MOS FET	Break Down Voltage	VL	100	V	
	Continuous Load Current	lι	100	mA	
	Pulse Load Current ^{*2} (AC/DC Connection)	ILP	260	mA	
	Power Dissipation	Po	180	mW/ch	
Isolation Voltage ^{*3}		BV	1 500	Vr.m.s.	
Total Power Dissipation		Рт	460	mW	
Operating Ambient Temperature		TA	-40 to +80	°C	
Storage Temperature		T _{stg}	-40 to +100	°C	

^{*1} PW = 100 μ s, Duty Cycle = 1 %

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^{*2} PW = 100 ms, 1 shot

^{*3} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output



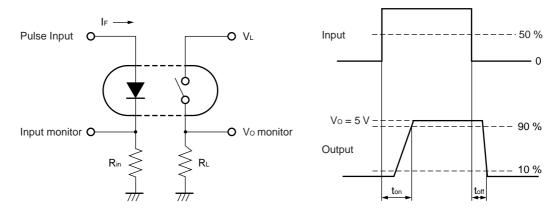
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

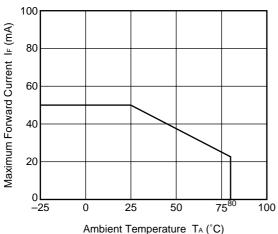
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V _R = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V _D = 100 V		0.03	1.0	μΑ
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		57		pF/ch
Coupled	LED On-state Current	IFon	IL = 100 mA			2.0	mA
	On-state Resistance	R _{on1}	IF = 10 mA, IL = 10 mA		3.4	6.0	Ω
		R _{on1}	$I_F = 10 \text{ mA}, I_L = 100 \text{ mA}, t \le 10 \text{ ms}$				
	Turn-on Time ^{*1}	ton	I _F = 10 mA, V _O = 5 V, PW ≥ 10 ms		0.16	1.0	ms
	Turn-off Time ^{*1}	t off			0.02	0.2	
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF/ch

*1 Test Circuit for Switching Time

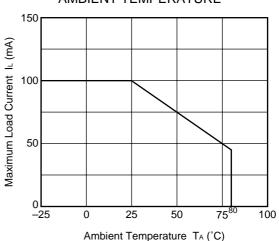


★ TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

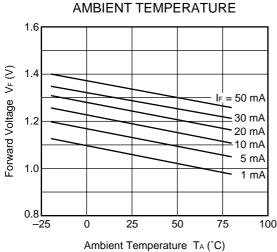




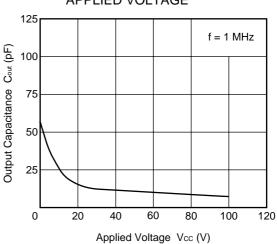
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



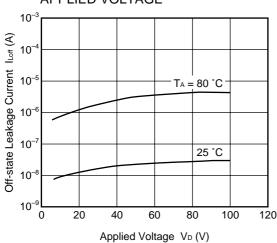
FORWARD VOLTAGE vs.



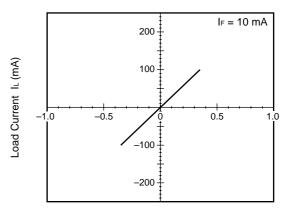
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



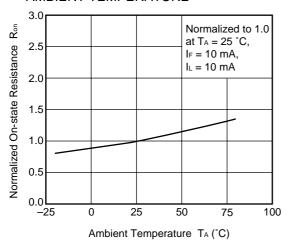
LOAD CURRENT vs. LOAD VOLTAGE



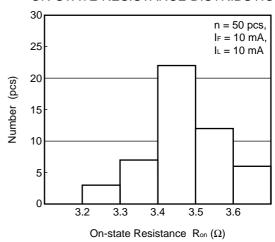
Load Voltage V_L (V)

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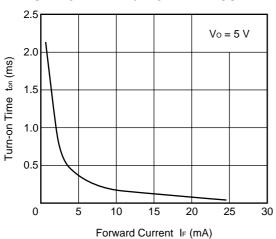
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



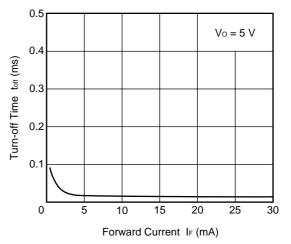
ON-STATE RESISTANCE DISTRIBUTION



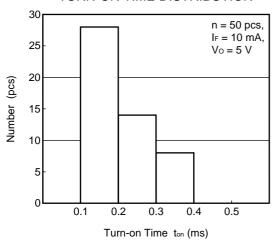
TURN-ON TIME vs. FORWARD CURRENT



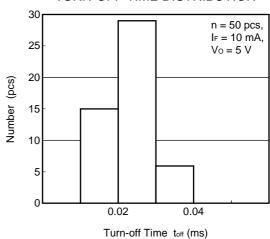
TURN-OFF TIME vs. FORWARD CURRENT



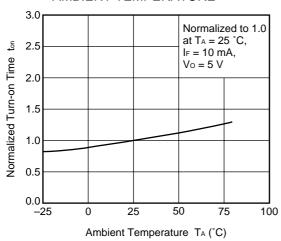
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

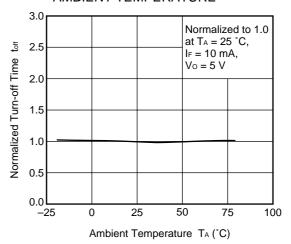


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

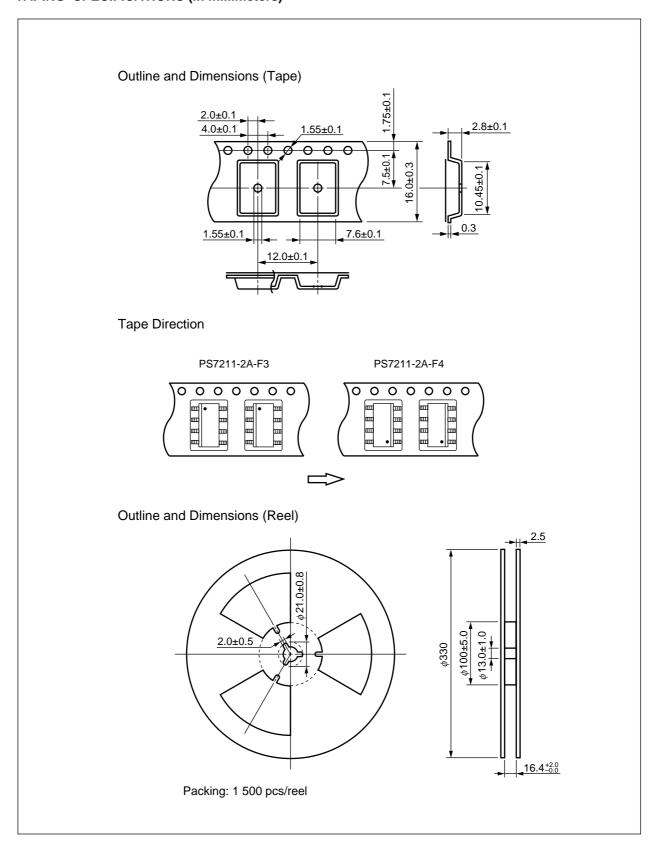


Remark The graphs indicate nominal characteristics.

NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



★ TAPING SPECIFICATIONS (in millimeters)





* RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

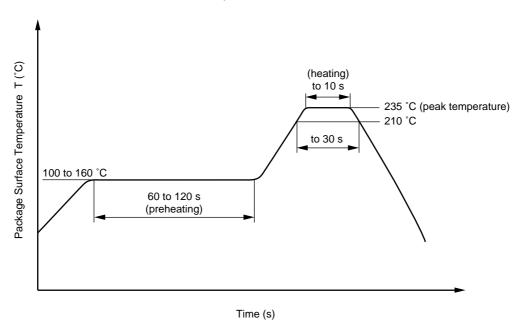
• Peak reflow temperature 235 °C (package surface temperature)

• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

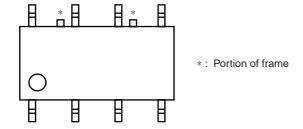
0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

Avoid shorting between portion of frame and leads.



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[MEMO]

NEC PS7211-2A

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CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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